Boundary Condition Independent Dynamic Compact Models of Packages and Heat Sinks from Thermal Transient Measurements

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Abstract

In this paper a methodology developed for the generation of transient compact models of packages and heat sinks from measured thermal transient results is described. The main advantage of generating dynamic compact models solely from measured results is the time-gain: the lengthy transient simulations, suggested by the DELPHI methodology can be omitted. After summarizing the procedure of generating the compact models of packages and heat sinks from measurements the use of the obtained dynamic compact package models in board level simulators, extended with the feature of calculating with compact models is presented.

1. Introduction

Compact thermal models of packages can be used not only for the characterization of packages, but they can be very useful substitutes of the detailed models in various simulations. Today board level simulators are being upgraded to simulate the behavior of printed circuit boards populated with packages, substituted by the compact models of their steady state or time dependent thermal behavior [1]. Compact models can be used also to model the packages in system level CFD simulations.

The best way for the creation of boundary condition independent compact models is a subject of dispute in the scientific literature for several years now, since the paper of Lasance et al [2]. This paper introduced a method that became later known as the DELPHI methodology. This methodology was elaborated for steady state representation of the packages only. It became extended with the procedure of adding capacitances to the steady state model in [4].

The steps of the DELPHI methodology are simulation, measurement, data fitting and optimization. To obtain data about the behavior of the package at various boundary conditions first of all a detailed structural model of the package has to be created. This model has to be simulated by a thermal solver. The appropriate set of boundary conditions for the simulation was defined in [2]. The simulated results have to be validated with and fitted to the measured results such, that some of the boundary conditions are used for the model fitting, some others are used for the validation of the model [3]. The compact model is constructed of a few circuit elements. The structure of this model is the descendent of the detailed model: in first approximation terminals (ports) are needed everywhere where boundary conditions are applied in the detailed model, but the optimization procedure may simplify the structure considerably.

The main advantage of the DELPHI methodology is delivering relatively accurate compact models for all boundary conditions. Especially the junction temperature accuracy is good for all the boundary conditions. But the creation of these models requires the generation of a detailed physical model, which is rather time consuming in case of complex structures. This is why in spite of all the advantages of the DELPHI method several other methods are appearing in the literature continuously, some of them have been obtaining really big attention like [5], or [6].

A group of the alternative methods wishes to eliminate the need of building the detailed model and the simulation. A typical representative is presented in [7]. The problem of this entirely measurement-based method is that the evaluation algorithm requires highly accurate measurement results, which is in general not easy to obtain.

In our recently developed methodology we combine the optimization strategy of the DELPHI methodology with the idea of using only measured results for the generation of the boundary condition independent dynamic compact models (DCMs) of [8].

2. The suggested methodology for DCM generation

In this method we try to keep all the advantages of the DELPHI method, while dropping the disadvantage: the need for detailed model generation, and the need for the extremely time consuming thermal transient simulation, and the need for model validation and model fitting.

The steps of our methodology are as follows:

1. Obtain all the transient curves that are needed for the optimization from high accuracy and high-resolution thermal transient measurements. For these measurements a limited subset of the boundary conditions, defined by the DELPHI methodology should be applied. Those, that were defined and recommended for the validation of the simulated detailed model of the package, namely, the double cold plate measurements defined as DCP1, DCP2, DCP3 and DCP4 in [3], see Table I.
2. Use a further developed version of the DOTCOMP tool described in [3] for fitting compact models to these measurements.
3. Verify the compact models with another set of measurements with further, new boundary conditions. The most critical part of the procedure is the verification of the measurements with new boundary conditions, since the measurements that are easy to realize are only those
DCPI, DCP2, DCP3 and DCP4 measurements that were used for the generation of the model. The realization of new, well-defined and reproducible boundary conditions is not easy in practice.

Table I. The prescribed heat transfer coefficient values in the dual cold plate measurements

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<thead>
<tr>
<th></th>
<th>$a_{up}$</th>
<th>$a_{bottom}$</th>
<th>$a_{side}$</th>
<th>$t_{leads}$</th>
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<tbody>
<tr>
<td>DCP-1</td>
<td>10000</td>
<td>10000</td>
<td>1</td>
<td>1</td>
</tr>
<tr>
<td>DCP-2</td>
<td>10</td>
<td>10000</td>
<td>1</td>
<td>1</td>
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<tr>
<td>DCP-3</td>
<td>10000</td>
<td>10</td>
<td>1</td>
<td>1</td>
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<tr>
<td>DCP-4</td>
<td>1</td>
<td>1</td>
<td>1</td>
<td>10000</td>
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A possible solution is to connect well-defined heat transfer coefficient values to the various package surfaces by e.g. heat sinks. The disadvantage of the method is that we need a series of heat sinks that have to be connected, mounted, dismounted to the package, rendering the measurement unreliable. A better solution is connecting controllable thermal resistances to the surfaces by the method presented in [9]. In this active heat sink realization the current of the Peltier cell is controlled such, that the ratio of the temperature drop on the Peltier cell and the heat flux crossing the cell is kept at a prescribed constant value, realizing this way an electronically adjustable constant heat resistance between the device and the ambience. The main advantage of this solution is that with the same measurement arrangement several a heat transfer coefficients, or $R_{th}$ values can be realized between the package and the cooling mount, that is, several thermal boundary conditions can be realized without dismounting the measurement arrangement, increasing strongly the reliability of measurement.

A pragmatic idea for the verification measurements is presented in [10]. This suggests finding the compact model of a heat sink with the same measurement and optimization method that is followed for the package. After this, connect the heat sink to the package, apply the same set of boundary conditions and find the compact model of the package + heat sink structure. If the compact model of the combined structure produces the same transient curves as the connected individual compact models of the package and the heat sink, then the compact models are considered verified.

3. Experimental results

The methodology of creating dynamic compact models is demonstrated for the case of a SOT-93 package of an NPN bipolar power transistor (BD245), presented in Figure 1. The characteristic faces of the package are named top, bottom and leads. For the model generation the thermal transient measurement results obtained in the DCP1, DCP2 and DCP3 double cold plate arrangements from the DELPHI boundary condition set, (see Table I) were used.

The actual realizations are shown in Figure 2. For the test set the transient results of 3 further arrangements were used: small and large refer to the application of a small and large heat sink on the top of the package, respectively, while the results designated by free refer to the measurement results of the free standing package.

A power step of 12 W was applied and the first 100 sec period of the thermal transient was captured real-time, with a high initial time resolution (1μsec) and high temperature resolution, measuring $V_{eb}$ “on-the-fly” as described in [11]. The measurement was followed by a post-processing step in the measurement software, automatically generating the descriptive functions of the packaged device, like the:
- transient response curves,
- time constant spectra of these, 
- the cumulative and differential structure functions.

The measured transient curves are shown in Figure 3. The DOTCOMP tool [3] was used to optimize the model. The input data to this program are the heat transfer coefficients on the characteristic faces and the total heat capacitance of the system. We found that the easiest way to create these input data is starting from the structure functions, introduced in [12], and discussed recently in [13]. The structure functions are graphic representations of the one dimensional equivalent detailed thermal RC network of the measured system. The heat transfer coefficients, the partial thermal resistance and the total system capacitance values can be directly read from them.
Figure 4 Cumulative structure functions of different thermal measurements on a BD245 transistor. DCP1 and DCP3 are the modeling boundary conditions, large, small and free belong to the testing boundary condition set.

It is easier to identify the interface between the sections using the derivative of this function, the differential structure function. In this function the peaks correspond to regions of high thermal conductivity, like a heat sink, and valleys show regions of low thermal conductivity, like die attach, see Figure 5. Characteristic points can be easily identified on the curves, these are points P, and 1 to 7. All curves nearly coincide from the junction to a peak near point P, this is the section of the common heat flow path. In case of this package there is a main heat flow path from the junction towards the copper base, which ends in the bottom face. The peak at P represents the mass of this copper base. At the ambience the thermal capacitance grows to infinity, the position of 1 and 4 shows the junction-to-ambience values for DCP1 and DCP3. From the P point we obtain $R_{th}=1.1$ K/W, and a cumulated capacitance for the whole package of $C_{th}=0.9$ W$^2$/K.$^2$.

Figure 5 Differential structure functions from the same measurements of the BD245 transistor. DCP1 and DCP3 are the modeling boundary conditions, large, small and free belong to the test boundary condition set.

The distance of $P$ to $I$ along the $x$ axis gives the case-to-cold-plate thermal resistance for DCP1 which is $R_{th}=0.45$ K/W, and about the same is obtained for DCP2. The $P$ to 4 distance gives $R_{th}=2.0$ K/W for DCP3. From the material parameters and the physical dimensions we can calculate the effective heat transfer coefficients. The bottom face is approximately $280$ mm$^2$, and the top face is approximately $200$ mm$^2$, consequently from $R_{th}$ and $R_{th}$, we get an $a$ of $8000$ W/Km$^2$ towards one side of the cold-plate. This is much below the $a$ heat transfer coefficient value represented by the BeO ceramics, so this value really shows the heat removal capability of the cold-plate.

The DOTCOMP program starts with the generation of the steady state model, and extends it to a dynamic model by adding capacitances to it, according to the procedure suggested in [4]. For the steady state model it assumes the model topology suggested in [3] and shown in Figure 6.

Figure 6 The initial model topology suggested by the DOTCOMP tool, J refers to the junction.
The tool first requires the steady-state temperatures of the model set and the $a$ values, represented by the $R_1$ and $R_2$ resistors in Figure 7. The $a$ values for the leads resistor were not obtained from DCP4 type (leads only) measurement, as suggested by the DELPHI methodology, since it was easy to calculate it from the wire geometry.

![SOT-93 diagram](image)

**Figure 7** The dynamic compact model optimized by DOTCOMP for the SOT-93 package from the measured data

As a result of the optimization process we obtained that the face-to-face resistances are high and can be omitted, see Figure 7, as we expected for this package structure. For the resistor values we got $R_s=1.3 \, \text{k}\Omega$, $R_f=7.0 \, \text{k}\Omega$, $R_p=18.05 \, \text{k}\Omega$.

These values were subdivided in the transient optimization process into two parts, giving the optimal locations for the capacitors for the best fit of the transient curves. The transient curve fitting was not extended to the time range below 0.1 ms, $C0$ was added manually for model consistency at short times.

The comparison of the measured curves and the ones calculated with the dynamic compact model by the board level solver of [1] is presented in Figure 8, where the applied power was 12W, $dep1m$ and $dep3m$ are the measured and $dep1s$ and $dep3s$ are the computed curves.

![Figure 8 Comparison of measured (dep1m, dep3m) and simulated (dep1s, dep3s) thermal transient curves](image)

**Figure 8** Comparison of measured (dep1m, dep3m) and simulated (dep1s, dep3s) thermal transient curves

A characteristic feature of compact modeling is presented in Figure 9: the compact models provide a good approximation of the behavior of the modeled system, but with the limited number of time constants of the DCM model the curves can not be as smooth as the ones they approximate.

The presented methodology can be followed for the generation of dynamic compact models of heat sinks as well. In case of heat sinks the use of a small transistor is recommended that we use for powering and measuring the temperature of the heat sink [10].

![Figure 9 differential structure functions calculated from the measured and simulated curves of Figure 8](image)

**Figure 9** Differential structure functions calculated from the measured and simulated curves of Figure 8

If we have heat sinks with known compact models we can validate the package compact models with new measurements, that are compared to new simulation results. In the new measurements we use the heat sinks as new boundary conditions to the package. These thermal transient curves have to be validated with the simulated results of the package + heat sink combined DCM that is obtained by the direct connection of the appropriate terminals of the compact models of the package and the heatsink. The results of this comparison are presented in Figure 10.

![Figure 10 Non-fitted measured and simulated results for the package + heat sink structure, for two different heat sink models, the package model is that of Figure 7](image)

**Figure 10** Non-fitted measured and simulated results for the package + heat sink structure, for two different heat sink models, the package model is that of Figure 7

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To obtain these curves we used a very simple model for the heat sinks: a parallel \( R_{\text{ch}} \) pair between the thermal ground and the sink surface node is connected with an \( R_{\text{hi}} \) element, representing the interface thermal resistance, to the package surface node. Such a simple model is shown in Figure 11 and Figure 12, where the actual value of \( R_{\text{hi}} = 0 \).

The agreement of the measured and simulated curves for the package + heat sink combined structure is very good for the case of the large heat sink, which shows that the package model is good. The small difference in the measured and simulated curves in case of the package + small heat sink arrangement can be attributed to the improper characterization of the small heat sink with the very simple model.

**Compact package model + heat sink model**

![Compact package model + heat sink model](image)

Figure 11 The concept of co-simulation of a detailed board model with dynamic compact models of packages and cooling assemblies such as heat-sinks

Figure 11 presents the board–package DCM co-simulation concept of [1]. The board model is populated with packages, some of them represented with their dynamic compact package models and some of these are terminated on their top surface with compact models of cooling mounts. The heat exchange between the packaged devices and the board takes place through the footprints of the packages. Further heat removal to the ambient can be modeled by heat transfer coefficients on the package surfaces (representing e.g. natural convection) or by the compact models of heat sinks, connected to the compact models of the packages.

In Figure 12 a simple model of a PGA package and a cooling mount are presented. The model library entry of the package is completed with the geometry of the footprints such as shown in Figure 13. In Figure 14 a simple, but demonstrative simulation example is shown: a steady-state temperature distribution of a board with two such PGA packages, dissipating both 1W. The package on the right is equipped with a cooling mount, resulting in less heat transferred to the board and lower junction temperatures. The same behavior can be observed on the junction temperature transients of Figure 15. Note Figure 15 in that the initial parts of the simulated transients coincide for shorter times, when the thermal wave propagates inside the package.

With the methodology of creating dynamic compact package models as well as compact models of cooling assemblies, we can create model libraries for thermal simulators that can co-simulate the detailed model of a PWB and the compact device models attached to it, like the THERMAN thermal simulator tool [14].

![Compact model example of a PGA package and a finned cooling mount](image)

Figure 12 Compact model example of a PGA package and a finned cooling mount

![Footprint geometry of the PGA package shown in Figure 12](image)

Figure 13 Footprint geometry of the PGA package shown in Figure 12

![Steady-state temperature distribution of a PWB showing also the junction temperatures in the packages. The package on the right has an attached heat-sink model of Figure 12.](image)

Figure 14 Steady-state temperature distribution of a PWB showing also the junction temperatures in the packages. The package on the right has an attached heat-sink model of Figure 12.
4. Conclusions

We have presented a methodology for creating dynamic compact thermal models of packages and/or cooling mounts entirely from measured thermal transient results. The idea is a derivative of the DEPHI methodology, adapted for convenient time dependent model generation. The main advantage of the presented methodology is that it does not request the creation of the detailed compact model, and the lengthy transient simulation is also substituted by fast transient measurements.

The use of the method is presented on the creation of a dynamic compact model for a SOT93 package. For the creation of the DCP model of the package the used measurement and model identification technique was the one derived from the structure functions derived by the evaluation of the measured high-resolution thermal transients.

The modeling approach presented here is another example of using structure functions: the major structural elements of the packaged device can be identified from them and the starting element values of a dynamic compact package model can also be found on them. The package models can be fine-tuned by proper fitting tools. In case of cooling assemblies the element values of a simple but sufficiently accurate compact model can be read directly from the structure functions obtained from measured thermal transient responses.

Attaching compact models of cooling assemblies to compact models of packages increases the accuracy of board-level simulators at virtually no cost in terms of CPU time, since during the co-simulation with the detailed model more than 99% of the CPU power is spent on solving the latter.

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References